



“XE52” Series

High Reliability Hybrid Microcircuit Crystal Oscillators

5.0V TTL, 5.0V HC/ACMOS, 3.3V, 2.5V & 1.8V LVHCMOS

Features

- High Shock & Vibration Design
- Tristate Output Option
- Radiation Tolerant to 10K Rads
- Low Profile Surface Mount, 0.160” Max. Height
- 100% Screening Options
- Low Phase Noise
- Hermetically Sealed, Ceramic Package
- ECCN: EAR99

Applications

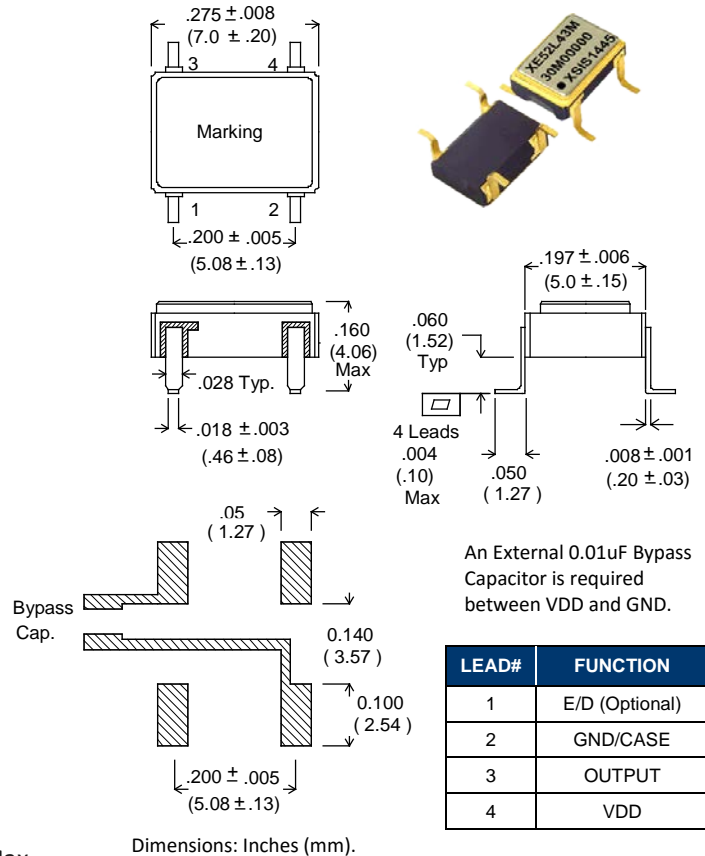
- High Shock & Vibration Applications
- Navigation Systems
- Aerospace Instrumentation
- Benign Space Applications
- Gun Launched Munitions

Package Specifications & Outline:

- Package: Ceramic 90% AL₂O₃
- Seal: Hermetic – Resistance Welded
- Weight: 0.25 Gms Typical, 0.3 Gms Max.
- Thermal Resistance, Junction to Case (θ_{JC}): 38 °C / Watt
- Solder Reflow, Temp./Time: 260 °C Max for 10 Seconds Max.
- Lead Material & Finish: Kovar, 40 to 70 μ inches gold over 100 to 250 μ inches Nickel,

Hot Solder Tinning per MIL-PRF-55310 is optional at additional cost.

Contact Xsis Electronics at xisis@xisis.com for any special requirements.

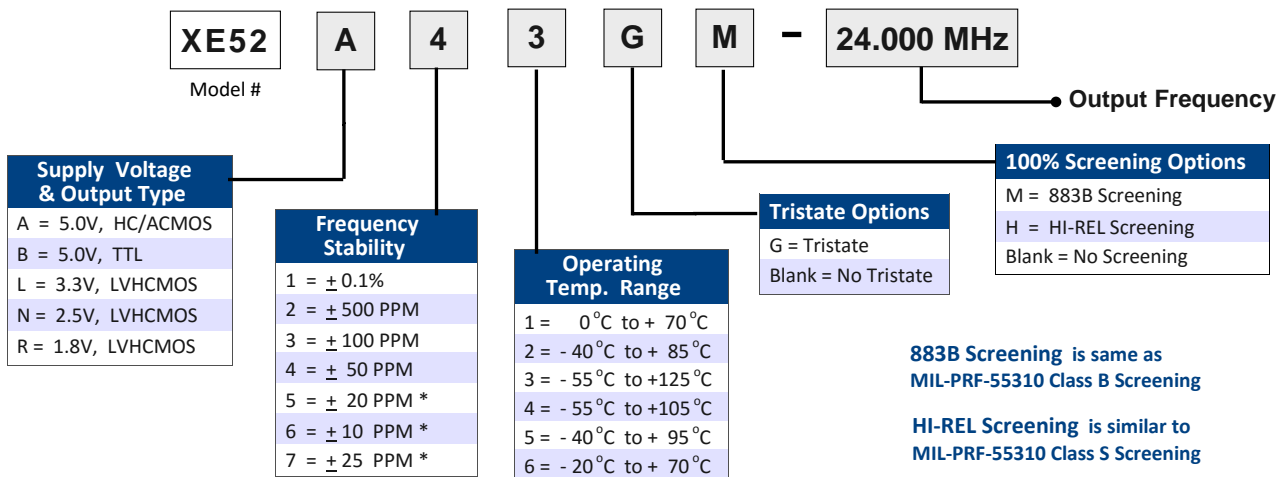


E/D (Enable/Disable) Input: A “Low” level at the input disables the Output into a high impedance state.

E/D Input has internal pull-up. It can be left floating or connected to Vdd.

ORDERING INFORMATION (Please build your part number from options below) :

P/N EXAMPLE: XE52A43GM - 24.000 MHz = 5.0V HC/ACMOS, ± 50 PPM over -55 °C to +125 °C, Tristate Output, 883B Screening, 24.000 MHz



* Frequency Stability Options 5, 6 & 7 are not available for all operating temperature ranges.



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Electrical Specifications, 5V TTL & 5V HC/ACMOS Oscillators:

Parameter	5 V TTL	5 V HC/ACMOS
Output Frequency Range	500 KHz - 100 MHz	500 KHz - 100 MHz
Frequency Accuracy at +25°C	± 15 PPM	± 15 PPM
Frequency Stability Vs Temperature	See Ordering Information on Page 1	
Operating Temperature Range	See Ordering Information on Page 1	
Supply Voltage (Vdd)	+ 5 VDC ± 10%	+ 5 VDC ± 10%
Input Current (no Load)	500 KHz - < 5 MHz 10 mA Max. 5 MHz - < 20 MHz 20 mA Max. 20 MHz - < 40 MHz 30 mA Max. 40 MHz - < 60 MHz 40 mA Max. 60 MHz - 100 MHz 60 mA Max.	500 KHz - < 5 MHz 10 mA Max. 5 MHz - < 20 MHz 20 mA Max. 20 MHz - < 40 MHz 30 mA Max. 40 MHz - < 60 MHz 40 mA Max. 60 MHz - 100 MHz 60 mA Max.
Output Waveform	Square Wave	Square Wave
Output Duty Cycle	60/40% Max. (at 1.4V Output Level)	< 40 MHz 55/45% Max. ≥ 40 MHz 60/40% Max. (at 50% Output Level)
Output High Level	2.5 V Min.	0.9 Vdd Min.
Output Low Level	0.5 V Max.	0.1 Vdd Max.
Output Load	TTL, 10 Loads Max. 50 pF Max. for <50 MHz	10K // 15 pF 50 pF Max. for <50 MHz
Rise & Fall Times (Typical Load)	< 30 MHz 6 nS Max. ≥ 30 MHz 3 nS Max. (0.8 to 2.0V Output Levels)	< 30 MHz 6 nS Max. ≥ 30 MHz 3 nS Max. (10% to 90% Output Levels)
Enable/Disable (E/D)	E/D Input ≥ 3.5V or Open : Normal Output E/D Input ≤ 0.8V: High Impedance	
Start-Up Time	10 mS Max.	10 mS Max.
Phase Jitter (10 KHz - 20 MHz Integ.)	0.35 pS rms Typical	0.35 pS rms Typical
Freq. Stability Vs Supply Voltage	± 4 PPM Max. for ± 10% change in Supply Voltage	
Aging at 70°C	± 3 PPM Max. first year, ± 2 PPM Max. per year thereafter	
Absolute Maximum Applied Voltage	+ 7VDC	+ 7VDC
Storage Temperature	-65°C to +125°C	-65°C to +125°C

For special requirements, such as, tighter output symmetry, faster start-up time, PIND screening, etc., please contact Xsis Electronics at xisis@xisis.com or call us at 913-631-0448.



“XE52” Series
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5.0V TTL, 5.0V HC/ACMOS, 3.3V, 2.5V & 1.8V LVHCMOS

Electrical Specifications, 3.3V, 2.5V & 1.8V LVHCMOS Oscillators:

Parameter	3.3V	2.5V	1.8V
Output Frequency Range	500 KHz to 160 MHz	500 KHz to 135 MHz	500 KHz to 100 MHz
Frequency Accuracy at +25 °C	± 15 PPM		
Frequency Stability Vs Temperature	See Ordering Information on Page 1		
Operating Temperature Range	See Ordering Information on Page 1		
Supply Voltage (Vdd)	3.3V ± 10%	2.5V ± 10%	1.8V ± 10%
Input Current (no Load)	500 KHz - 8 MHz 3 mA Max. 8.1 MHz - 16 MHz 6 mA Max. 16.1 MHz - 32 MHz 10 mA Max. 32.1 MHz - 60 MHz 20 mA Max. 60.1 MHz - 100 MHz 30 mA Max. 100.1 MHz - 130 MHz 40 mA Max. 130.1 MHz - 160 MHz 50 mA Max	500 KHz - 8 MHz 3 mA Max. 8.1 MHz - 16 MHz 4 mA Max. 16.1 MHz - 32 MHz 8 mA Max. 32.1 MHz - 60 MHz 15 mA Max. 60.1 MHz - 100 MHz 20 mA Max. 100.1 MHz - 135 MHz 30 mA Max.	500 KHz - 8 MHz 3 mA Max. 8.1 MHz - 16 MHz 4 mA Max. 16.1 MHz - 32 MHz 6 mA Max. 32.1 MHz - 60 MHz 10 mA Max. 60.1 MHz - 85 MHz 20 mA Max. 85.1 MHz - 100 MHz 25 mA Max.
Output Waveform	Square Wave		
Output Duty Cycle (at 50% Output Level)	< 40 MHz 55/45% ≥ 40 MHz 60/40%	< 40 MHz 55/45% ≥ 40 MHz 60/40%	< 40 MHz 55/45% ≥ 40 MHz 60/40%
Output High Level	0.9 Vdd Min.		
Output Low Level	0.1 Vdd Max.		
Output Load	10K // 15 pF		
Rise & Fall Times (Typical Load)	< 40 MHz 6 nS Max. ≥ 40 MHz 3 nS Max. (10% to 90% Output Levels)		
Enable/Disable (E/D)	E/D Input ≥ 0.7 Vdd or Open : Normal Output E/D Input ≤ 0.3 Vdd: High Impedance		
Start-Up Time	10 mS Max.		
Phase Jitter (10 KHz - 20 MHz Integ.)	0.35 pS rms Typical		
Freq. Stability Vs Supply Voltage	± 4 PPM Max. for ± 10% change in Supply Voltage		
Aging at 70 °C	± 3 PPM Max. first year, ± 2 PPM Max. per year thereafter		
Absolute Maximum Applied Voltage	+5.0 VDC		
Storage Temperature	-65 °C to +125 °C		

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Packaging: Tape & Reel, See Page 5

Thermal Characteristics:

Junction to case Thermal Constant (θ_{JC}): 38 °C / Watt

Junction to Ambient (Device floating in free air) Thermal Constant (θ_{JA}): 136 °C / Watt

Hi-Rel Screening:

When HI-REL option is selected, Xsis Oscillators are subjected to 100% screening similar to Class “S” screening in accordance with MIL-PRF-55310. Refer to www.xsis.com for additional details about HI-REL screening.

Typical Phase Noise (dbc/Hz):

	10 Hz	100 Hz	1 KHz	10 KHz	100 KHz	1 MHz
10 MHz	-109	-140	-157	-162	-163	-164
25 MHz	-100	-127	-151	-158	-160	-162
50 MHz	-89	-117	-148	-157	-159	-160
96 MHz	-80	-107	-139	-151	-156	-158
110 MHz	-75	-102	-130	-142	-149	-153

Environmental Specifications:

XE52 series oscillators are designed to meet or exceed the Environmental tests specified below. Customized screening and environmental testing are also available to meet your special requirements.

Test	Test Conditions
Vibration	0.06” DA, 30 G peak, 10 - 2000 Hz, MIL-STD-202, Method 204, Cond. G
Shock	1500 G, 0.5 mS, half-Sine, MIL-STD-883, Method 2002, Cond. B
Temperature Cycling	MIL-STD-883, Method 1010, Cond. C
Thermal Shock	MIL-STD-202, Method 107, Cond. B
Seal (Fine and Gross)	MIL-STD-883, Method 1014 Cond. A & C
Burn-in	160 Hours, 125 °C, Nominal Supply Voltage & Load
Frequency Aging	30 days at 70 °C, ± 1.5 PPM Max.
Altitude	MIL-STD-202, Method 105, Cond. C
Constant Acceleration	MIL-STD-883, Method 2001, 5000 G
Moisture Resistance	MIL-STD-202, Method 106, Vibration Sub Cycle Omitted
Solderability	MIL-STD-202, Method 208
Resistance to Soldering Heat	MIL-STD-202, Method 210, Cond B. or C as applicable
Resistance to Solvents	MIL-STD-202, Method 215
Internal Water Vapor Content	MIL-STD-883, Method 1018
ESD Classification	MIL-STD-883, Method 3015, Class 1C, HBM 1000 to 1999
Moisture Sensitivity Level	J-STD-020, MSL=1

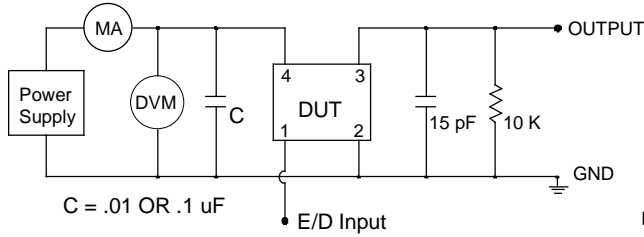


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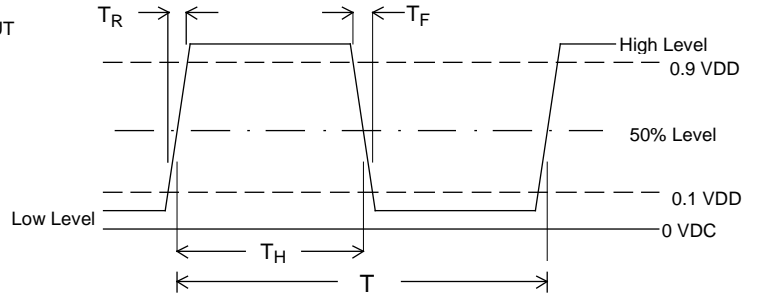
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HCMOS Test Circuit



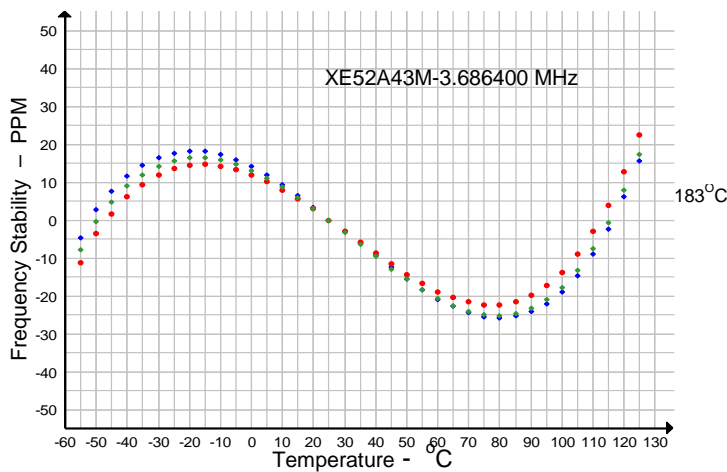
E/D (Enable/Disable) Input has an internal pull-up resistor. It can be left floating or connected to Vdd.

HCMOS Output Waveform

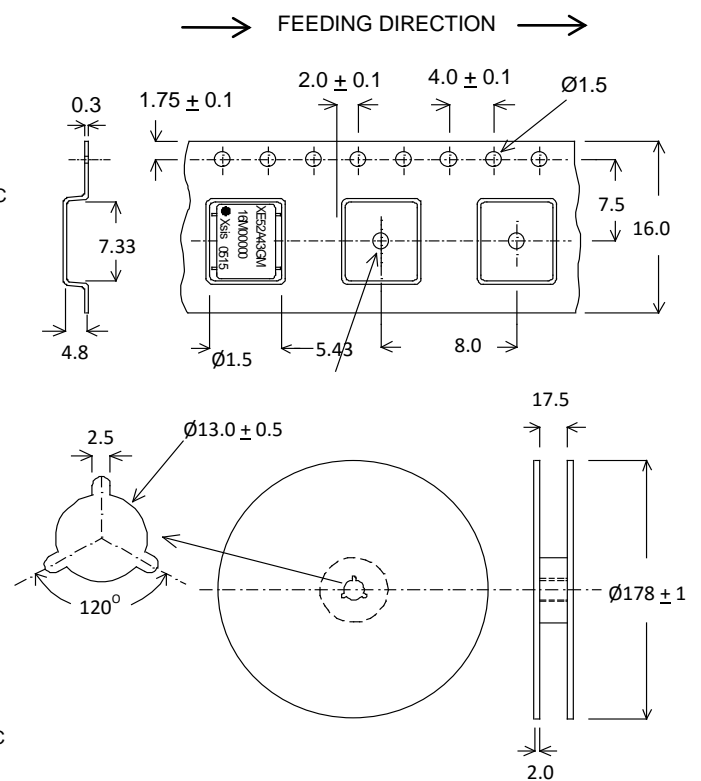


$$\text{Symmetry} = \frac{T_H}{T} \times 100 \%$$

Typical Freq. Stability Vs. Temperature

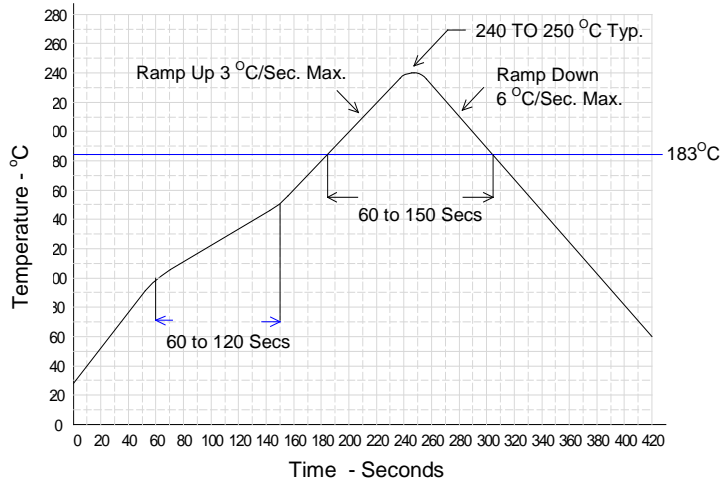


Tape & Reel Information



Dimensions are in mm.

Typical Solder Reflow Profile



Tape is EIA-481-A Compliant.